



40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C (Note 6)
-40V	$25m\Omega$ @ $V_{GS} = -10V$	- 7.2A
-40 V	$45m\Omega$ @ V _{GS} = -4.5V	- 5.4A

Description and Application

This MOSFET has been designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

Features and Benefits

- Low R_{DS(ON)} Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part.
 A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMP4025SFGQ</u>)

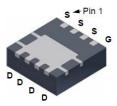
Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.0172 grams (Approximate)

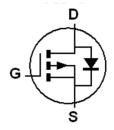




Top View



Bottom View



Device Symbol

Ordering Information (Note 4)

Part Number	Paakaga	Pac	king
Part Number	Package	Qty.	Carrier
DMP4025SFG-7	PowerDI3333-8	2,000	Reel
DMP4025SFG-13	PowerDI3333-8	3,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

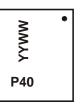
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DMP4025SFG Document Number: DS36107 Rev: 4 - 2



Marking Information

Site 1



P40 = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 22 = 2022) WW = Week (01 to 53)

Site 2



P40 = Product Type Marking Code
YWX = Date Code Marking
Y = Year (ex: 2 = 2022)
W = Week (ex: a = Week 27; z Represents Week 52 and 53)
X = Internal Code (ex: U = Monday)

Date Code Key

Year	2012	 2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	2	 2	3	4	5	6	7	8	9	0	1

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	X	Υ	Z

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characterist	Symbol	Value	Unit	
Drain-Source Voltage	Drain-Source Voltage			V
Gate-Source Voltage	V _{GSS}	±20]	
Operation and Departs Operated No.	(Note 6)		-7.2	
Continuous Drain Current, V _{GS} = -10V	$T_A = +70^{\circ}C \text{ (Note 6)}$	ID	-5.77	
	(Note 5)		-4.65	_
Maximum Body Diode Forward Current	(Note 6)	Is	-7.2	A
Pulsed Drain Current	(Note 7)	I _{DM}	-80	
Pulsed Source Current	(Note 7)	Ism	-80	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

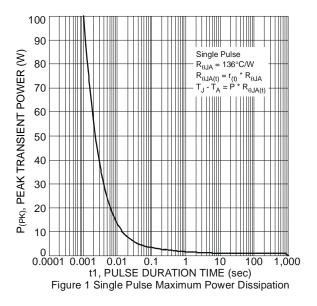
Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	0.81	W	
Linear Derating Factor	(Note 6)	PD	1.95	l vv	
Thermal Desistance, Junction to Ambient	(Note 5)	D	155	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	64		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. For a device surface mounted on 25mm x 25mm FR-4 PCB with 2oz copper, in still air conditions.
- 7. Same as note (6), except the device is pulsed with D= 0.02 and pulse width $300 \mu s$.



Thermal Characteristics



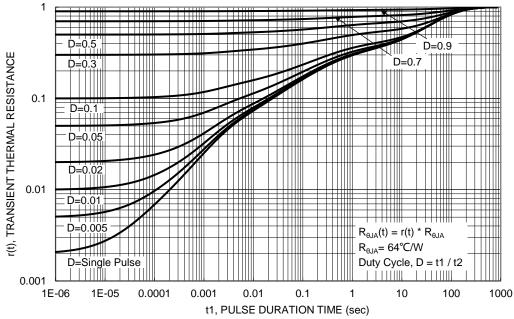


Figure 2. Transient Thermal Resistance



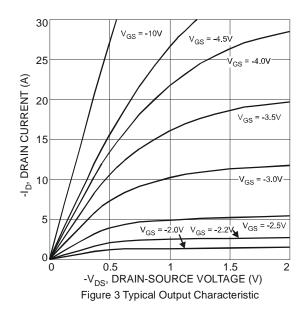
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

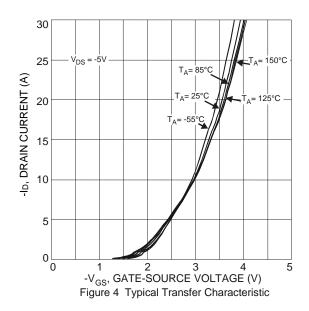
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$I_D = -250 \mu A, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μΑ	V _{DS} = -40V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS						•	
Gate Threshold Voltage	Vgs(TH)	-0.8	-1.3	-1.8	V	$I_D = -250\mu A$, $V_{DS} = V_{GS}$	
Static Dunin Course On Benintanae (Note 2)	D		18	25	mΩ	$V_{GS} = -10V, I_{D} = -3A$	
Static Drain-Source On-Resistance (Note 8)	R _{DS(ON)}		30	45	11122	Vgs = -4.5V, ID = -3A	
Forward Transconductance (Notes 8 & 9)	g fs	_	16.6		S	$V_{DS} = -5V, I_{D} = -3A$	
Diode Forward Voltage (Note 8)	VsD	_	-0.7	-1.0	V	Is = -1A, V _G S = 0V	
DYNAMIC CHARACTERISTICS (Note 9)						•	
Input Capacitance	Ciss	_	1643			$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	179		pF		
Reverse Transfer Capacitance	Crss	_	128	_		I = TIVII IZ	
Gate Resistance	R_g	_	6.43		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (Note 10)	Qg	_	14.0	_		Vgs = -4.5V	
Total Gate Charge (Note 10)	Qg	_	33.7	_	~C	V _{DS} = -20V	
Gate-Source Charge (Note 10)	Qgs	_	5.5	_	$ \begin{array}{c c} & \text{nC} \\ \hline & \text{VGS} = -10V \\ \hline & \text{ID} = -3A \end{array} $		
Gate-Drain Charge (Note 10)	Qgd	_	7.3	_			
Turn-On Delay Time (Note 10)	td(ON)	_	6.9	_		V _{DD} = -20V, V _{GS} = -10V	
Turn-On Rise Time (Note 10)	tR	_	14.7	_			
Turn-Off Delay Time (Note 10)	t _{D(OFF)}	_	53.7	_	ns	$I_D = -3A$	
Turn-Off Fall Time (Note 10)	tF	_	30.9	_			

Notes:

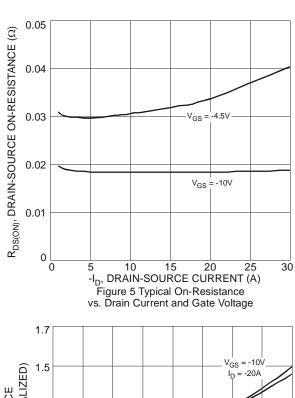
- 8. Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%.$
- 9. For design aid only, not subject to production testing.
 10. Switching characteristics are independent of operating junction temperatures.

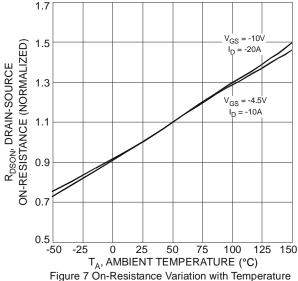
Typical Characteristics

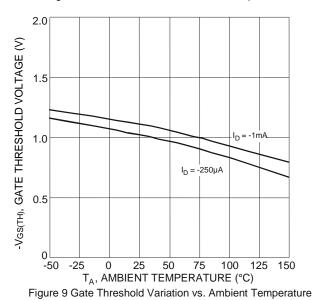


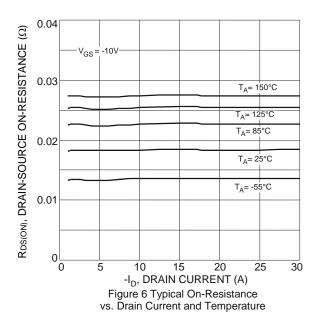


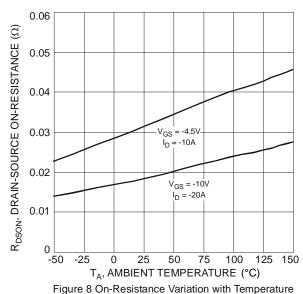






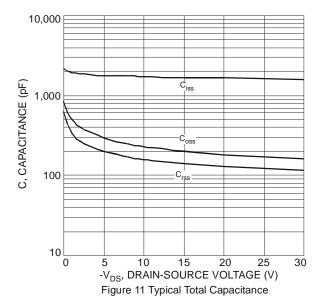


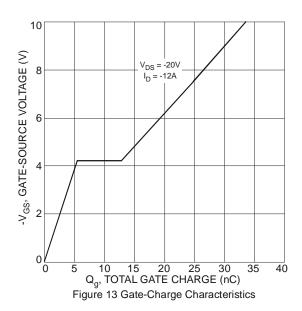


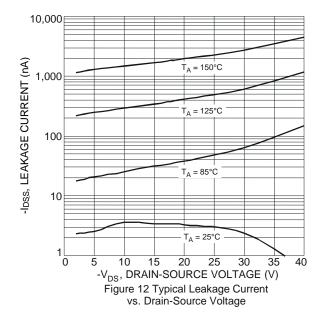


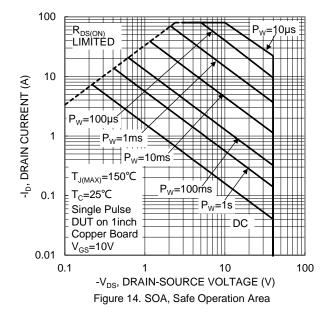
20 18 16 16 14 12 12 12 10 10 8 8 4 2 0 0.2 0.4 0.6 0.8 1.0 1.2 -V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 10 Diode Forward Voltage vs. Current









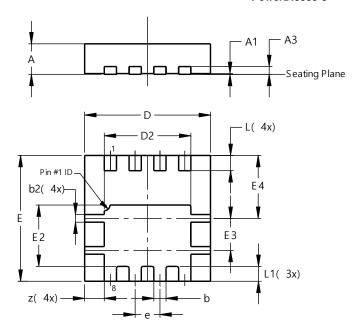




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

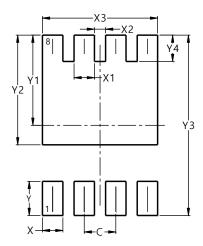


	PowerDI3333-8						
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.02				
A3	_	_	0.203				
b	0.27	0.37	0.32				
b2	0.15	0.25	0.20				
D	3.25	3.35	3.30				
D2	2.22	2.32	2.27				
E	3.25	3.35	3.30				
E2	1.56	1.66	1.61				
E3	0.79	0.89	0.84				
E4	1.60	1.70	1.65				
е	-	-	0.65				
L	0.35	0.45	0.40				
L1	_	_	0.39				
Z	_	_	0.515				
All I	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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